Claims

- 1. An organic electroluminescent device comprising: an organic thin-film transistor element including at least an active layer made of an organic material; and an organic electroluminescent element driven by the organic thin-film transistor element.
- 2. The organic electroluminescent device according to Claim 1, further comprising a substrate, wherein the organic electroluminescent element is provided between the substrate and the organic thin-film transistor element.
- 3. The organic electrolumines cent device according to Claim 1, further comprising a substrate, wherein the organic thin-film transistor element is provided between the substrate and the organic electroluminescent element.
- 4. The organic electroluminescent device according to any one of Claims 1 to 3, wherein, in each pixel, the total area of the area of a source region and the area of a drain region of the organic thin-film transistor element is larger than the area of a region provided with a luminescent material of the organic electroluminescent element.
- 5. The organic electroluminescent device according to any one of Claims 1 to 4, wherein the source and the drain, which constitute the organic thin-film transistor element, have bent parts that face each other at a predetermined spacing.
- 6. The organic electroluminescent device according to Claim 5, wherein a gate is provided so as to cover the bent parts of the source

and the drain.

- 7. The organic electrologinescent device according to Claim 5 or Claim 6, wherein the bent parts of the source and the drain are provided in a comb-shape and face each other at a predetermined spacing.
- 8. The organic electroluminescent device according to Claim 5 or Claim 6, wherein the bent parts of the source and the drain are provided in a spiral-shape and face each other at a predetermined spacing.
- 9. A method of manufacturing an organic electroluminescent device, comprising: a step of forming an organic electroluminescent element above a substrate; and a step of forming an organic thin-film transistor element, for driving the organic electroluminescent element, above the organic electroluminescent element.
- 10. A method of manufacturing an organic electroluminescent device, comprising: a step of forming an organic thin-film transistor element above a substrate; and a step of forming an organic electroluminescent element, which is driven by the organic thin-film transistor element and performs predetermined display, above the organic thin-film transistor element.
- 11. The method of manufacturing an organic electroluminescent device according to Claim 9 or Claim 10, wherein, in each pixel, the total area of the area of a source region and the area of a drain region of the organic thin-film transistor element is larger than the area of a region provided with a luminescent material.
 - 12. The method of manufacturing an organic electroluminescent

device according to any one of Claims 9 to 11, wherein the source and the drain, which constitute the organic thin-film transistor element, have bent parts that face each other at a predetermined spacing.

- 13. The method of manufacturing an organic electroluminescent device according to Claim 12, wherein a gate is provided so as to cover the bent parts of the source and the drain.
- 14. The method of manufacturing an organic electroluminescent device, according to Claim 12 or Claim 13, wherein the bent parts of the source and the drain are provided in a comb-shape and face each other at a predetermined spacing.
- 15. The method of manufacturing an organic electroluminescent device, according to Claim 12 or Claim 13, wherein the bent parts of the source and the drain are provided in a spiral-shape and face each other at a predetermined spacing.
- device, according to any one of Claims 9 to 15, wherein, at least the organic thin-film transistor and an organic-luminescent layer of the organic electroluminescent element are formed by a liquid-phase process.
- 17. An electronic apparatus comprising an electroluminescent device according to any one of Claims 1 to 8.

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